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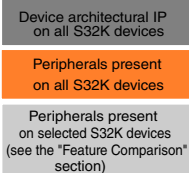
What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex® -M4F
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, FlexIO, I ² C, LINbus, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	58
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b SAR; D/A1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/fs32k144hat0vlht



2 Feature comparison

NOTE

Availability of peripherals depends on the pin availability in a particular package. For more information see *IO Signal*

3 Ordering information

3.1 Selecting orderable part number

Not all part number combinations are available. See the attachment *S32K1xx_Orderable_Part_Number_List.xlsx* attached with the Datasheet for a list of standard orderable part numbers.

5. V_{REFH} should always be equal to or less than $V_{DDA} + 0.1\text{ V}$ and $V_{DD} + 0.1\text{ V}$
6. Open drain outputs must be pulled to V_{DD} .
7. When input pad voltage levels are close to V_{DD} or V_{SS} , practically no current injection is possible.

4.3 Thermal operating characteristics

Table 3. Thermal operating characteristics for 64 LQFP, 100 LQFP, and 100 MAP-BGA packages.

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
T_A C-Grade Part	Ambient temperature under bias	-40	—	85 ¹	°C
T_J C-Grade Part	Junction temperature under bias	-40	—	105 ¹	°C
T_A V-Grade Part	Ambient temperature under bias	-40	—	105 ¹	°C
T_J V-Grade Part	Junction temperature under bias	-40	—	125 ¹	°C
T_A M-Grade Part	Ambient temperature under bias	-40	—	125 ²	°C
T_J M-Grade Part	Junction temperature under bias	-40	—	135 ²	°C

1. Values mentioned are measured at $\leq 112\text{ MHz}$ in HSRUN mode.
2. Values mentioned are measured at $\leq 80\text{ MHz}$ in RUN mode.

Table 7. Power consumption (Typicals unless stated otherwise) 1 (continued)

Chip/Device	Ambient Temperature (°C)		VLPS (µA) ²		VLPR (mA)			STOP1 (mA)	STOP2 (mA)	RUN@48 MHz (mA)		RUN@64 MHz (mA)		RUN@80 MHz (mA)		HSRUN@112 MHz (mA) ³		IDD/MHz (µA/MHz) ⁴
			Peripherals disabled ⁵	Peripherals enabled	Peripherals disabled ⁶	Peripherals enabled use case ¹⁶	Peripherals enabled use case ²⁷			Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	
	105	Max	1660	1736	3.48	3.55	NA	14.5	15.6	34.8	43.6	41.9	53.9	48.7	65.1	70.4	96.1	609
		Typ	560	577	2.49	2.54	4.03	10.9	11.9	29.8	37.8	37.6	47.5	45.2	61.5	63.8	89.1	565
		Max	2945	2970	4.40	4.47	NA	18.0	19.0	38.4	46.8	44.9	55.3	51.6	66.8	73.6	97.4	645
	125	Typ	NA	NA	NA	NA	4.85	NA	NA	NA	NA	NA	NA	NA	NA	NA	NA	NA
		Max	3990	4166	6.00	6.08	NA	23.4	24.5	44.3	52.5	50.9	61.3	57.5	71.6	NA	NA	719

1. Typical current numbers are indicative for typical silicon process and may vary based on the silicon distribution and user configuration. Typical conditions assumes $V_{DD} = V_{DDA} = V_{REFH} = 5\text{ V}$, temperature = 25 °C and typical silicon process unless otherwise stated. All output pins are floating and On-chip pulldown is enabled for all unused input pins.
2. Current numbers are for reduced configuration and may vary based on user configuration and silicon process variation.
3. HSRUN mode must not be used at 125°C. Max ambient temperature for HSRUN mode is 105°C.
4. Values mentioned for S32K14x devices are measured at RUN@80 MHz with peripherals disabled and values mentioned for S32K11x devices are measured at RUN@48 MHz with peripherals disabled.
5. With PMC_REGSC[CLKBIASDIS] set to 1. See Reference Manual for details.
6. Data collected using RAM
7. Numbers on limited samples size and data collected with Flash
8. The S32K148 data points assume that ENET/QuadSPI/SAI etc. are inactive.

5 I/O parameters

5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.

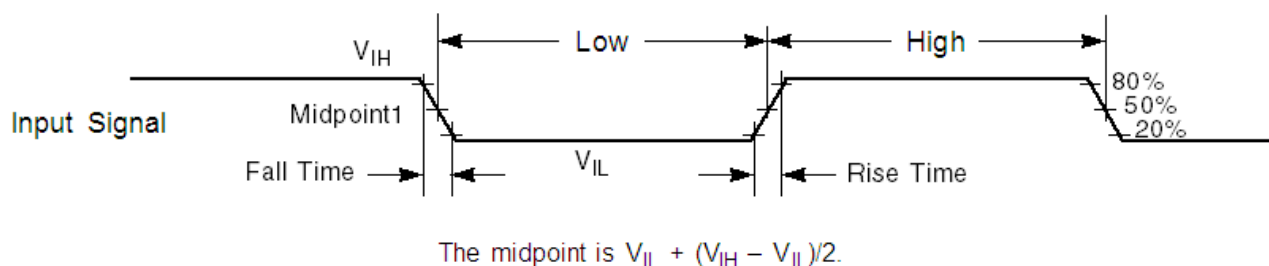


Figure 7. Input signal measurement reference

5.2 General AC specifications

These general purpose specifications apply to all signals configured for GPIO, UART, and timers.

Table 10. General switching specifications

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1, 2
	GPIO pin interrupt pulse width (digital glitch filter disabled, passive filter disabled) — Asynchronous path	50	—	ns	3
WFRST	$\overline{\text{RESET}}$ input filtered pulse	—	10	ns	4
WNFRST	$\overline{\text{RESET}}$ input not filtered pulse	Maximum of (100 ns, bus clock period)	—	ns	5

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop and VLPS modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater of synchronous and asynchronous timing must be met.
3. These pins do not have a passive filter on the inputs. This is the shortest pulse width that is guaranteed to be recognized.
4. Maximum length of $\overline{\text{RESET}}$ pulse which will be filtered by internal filter.
5. Minimum length of $\overline{\text{RESET}}$ pulse, guaranteed not to be filtered by the internal filter. This number depends on bus clock period also. For example, in VLPR mode bus clock is 4 MHz, which make clock period of 250 ns. In this case, minimum pulse width which will cause reset is 250 ns. For faster bus clock frequencies which have clock period less than 100 ns, the minimum pulse width not filtered will be 100 ns.

I/O parameters

- Several I/O have both high drive and normal drive capability selected by the associated Portx_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details see IO Signal Description Input Multiplexing sheet(s) attached with the *Reference Manual*.
- When using ENET and SAI on S32K148, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
- Measured at input $V = V_{SS}$
- Measured at input $V = V_{DD}$

5.4 DC electrical specifications at 5.0 V Range

Table 12. DC electrical specifications at 5.0 V Range

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V_{DD}	I/O Supply Voltage	4	—	5.5	V	
V_{ih}	Input Buffer High Voltage	$0.65 \times V_{DD}$	—	$V_{DD} + 0.3$	V	1
V_{il}	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.35 \times V_{DD}$	V	2
V_{hys}	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
I_{ohGPIO} $I_{ohGPIO-HD_DSE_0}$	I/O current source capability measured when pad $V_{oh} = (V_{DD} - 0.8 \text{ V})$	5	—	—	mA	
I_{olGPIO} $I_{olGPIO-HD_DSE_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	5	—	—	mA	
$I_{ohGPIO-HD_DSE_1}$	I/O current source capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	20	—	—	mA	3
$I_{olGPIO-HD_DSE_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20	—	—	mA	3
$I_{ohGPIO-FAST_DSE_0}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	14.0	—	—	mA	4
$I_{olGPIO-FAST_DSE_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	14.5	—	—	mA	4
$I_{ohGPIO-FAST_DSE_1}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	21	—	—	mA	4
$I_{olGPIO-FAST_DSE_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20.5	—	—	mA	4
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5 \text{ V}$					5
	All pins other than high drive port pins		0.005	0.5	μA	
	High drive port pins		0.010	0.5	μA	
R_{PU}	Internal pullup resistors	20		50	$k\Omega$	6
R_{PD}	Internal pulldown resistors	20		50	$k\Omega$	7

- For reset pads, same V_{ih} levels are applicable
- For reset pads, same V_{il} levels are applicable
- The strong pad I/O pin is capable of switching a 50 pF load up to 40 MHz.
- For reference only. Run simulations with the IBIS model and custom board for accurate results.

Table 16. Device clock specifications 1 (continued)

Symbol	Description	Min.	Max.	Unit
f _{FLASH}	Flash clock	—	24	MHz
Normal run mode (S32K14x series) ³				
f _{SYS}	System and core clock	—	80	MHz
f _{BUS}	Bus clock	—	40 ⁴	MHz
f _{FLASH}	Flash clock	—	26.67	MHz
VLPR mode ⁵				
f _{SYS}	System and core clock	—	4	MHz
f _{BUS}	Bus clock	—	4	MHz
f _{FLASH}	Flash clock	—	1	MHz
f _{ERCLK}	External reference clock	—	16	MHz

1. Refer to the section [Feature comparison](#) for the availability of modes and other specifications.
2. Only available on some devices. See section [Feature comparison](#).
3. With SPLP as system clock source.
4. 48 MHz when f_{SYS} is 48 MHz
5. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

6 Peripheral operating requirements and behaviors

6.1 System modules

There are no electrical specifications necessary for the device's system modules.

6.2 Clock interface modules

6.2.1 External System Oscillator electrical specifications

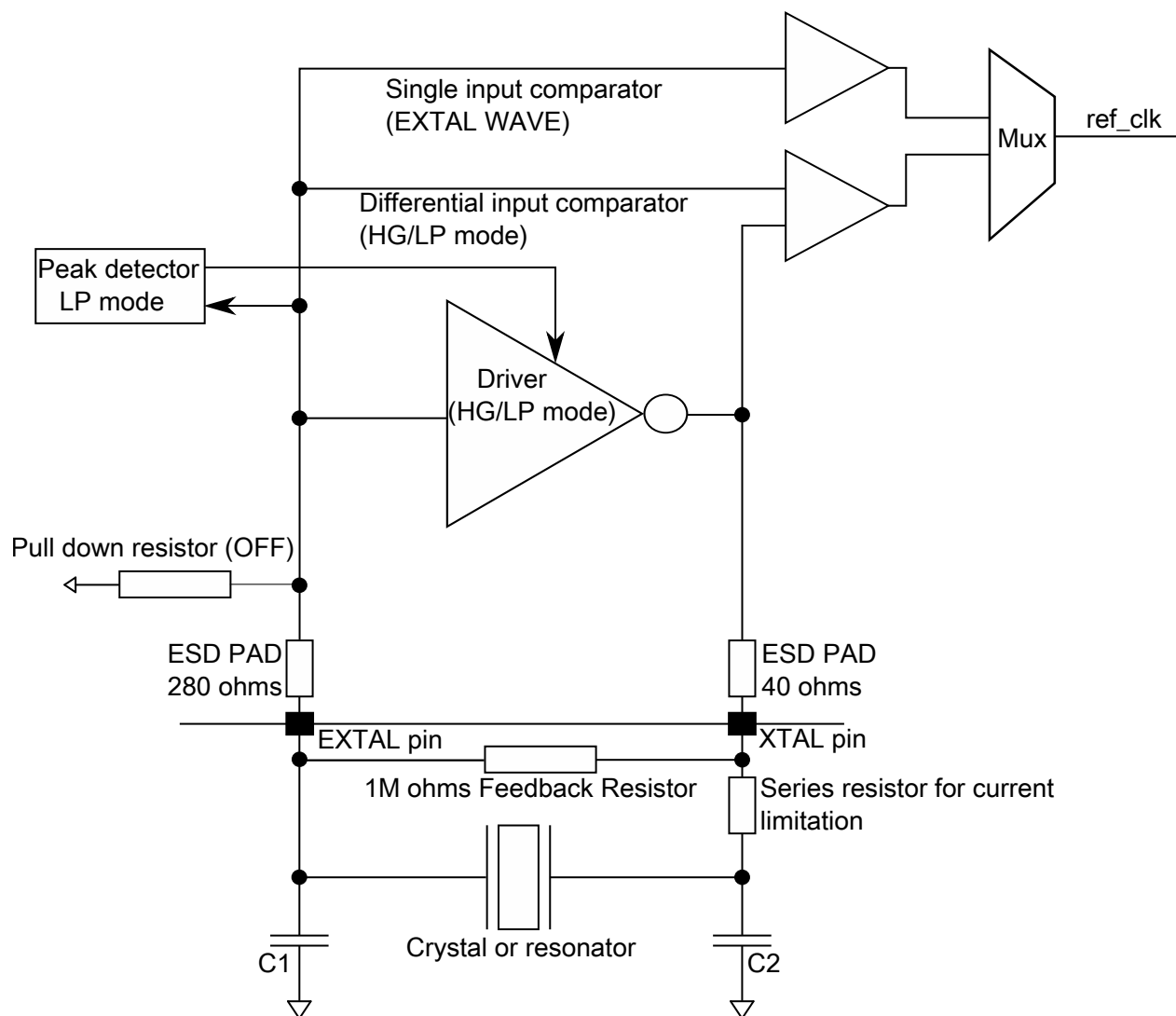


Figure 8. Oscillator connections scheme

Table 17. External System Oscillator electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
g_{mXOSC}	Crystal oscillator transconductance					
	SCG_SOSCCFG[RANGE]=2'b10 for 4-8 MHz	2.2	—	13.7	mA/V	
	SCG_SOSCCFG[RANGE]=2'b11 for 8-40 MHz	16	—	47	mA/V	
V_{IL}	Input low voltage — EXTERNAL pin in external clock mode	V_{SS}	—	1.15	V	
V_{IH}	Input high voltage — EXTERNAL pin in external clock mode	$0.7 \cdot V_{DD}$	—	V_{DD}	V	
C_1	EXTERNAL load capacitance	—	—	—		1
C_2	XTAL load capacitance	—	—	—		1
R_F	Feedback resistor					2
	Low-gain mode (HGO=0)	—	—	—	MΩ	

Table continues on the next page...

6.2.3 System Clock Generation (SCG) specifications

6.2.3.1 Fast internal RC Oscillator (FIRC) electrical specifications

Table 19. Fast internal RC Oscillator electrical specifications

Symbol	Parameter ¹	Value			Unit
		Min.	Typ.	Max.	
F_{FIRC}	FIRC target frequency	—	48	—	MHz
ΔF	Frequency deviation across process, voltage, and temperature < 105°C	—	±0.5	±1	% F_{FIRC}
ΔF_{125}	Frequency deviation across process, voltage, and temperature < 125°C	—	±0.5	±1.1	% F_{FIRC}
T_{Startup}	Startup time		3.4	5	μs ²
T_{JIT}^3	Cycle-to-Cycle jitter	—	300	500	ps
T_{JIT}^3	Long term jitter over 1000 cycles	—	0.04	0.1	% F_{FIRC}

1. With FIRC regulator enable

2. Startup time is defined as the time between clock enablement and clock availability for system use.

3. FIRC as system clock

NOTE

Fast internal RC Oscillator is compliant with CAN and LIN standards.

6.2.3.2 Slow internal RC oscillator (SIRC) electrical specifications

Table 20. Slow internal RC oscillator (SIRC) electrical specifications

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
F_{SIRC}	SIRC target frequency	—	8	—	MHz
ΔF	Frequency deviation across process, voltage, and temperature < 105°C	—	—	±3	% F_{SIRC}
ΔF_{125}	Frequency deviation across process, voltage, and temperature < 125°C	—	—	±3.3	% F_{SIRC}
T_{Startup}	Startup time	—	9	12.5	μs ¹

1. Startup time is defined as the time between clock enablement and clock availability for system use.

Table 25. NVM reliability specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
When using FlexMemory feature : FlexRAM as Emulated EEPROM						
t_{nvmretee}	Data retention	5	—	—	years	4
$n_{\text{nvmwree16}}$	Write endurance	100 K	—	—	writes	5, 6, 7
$n_{\text{nvmwree256}}$	• EEPROM backup to FlexRAM ratio = 16 • EEPROM backup to FlexRAM ratio = 256	1.6 M	—	—	writes	

1. Data retention period per block begins upon initial user factory programming or after each subsequent erase.
2. Program and Erase for PFlash and DFlash are supported across product temperature specification in Normal Mode (not supported in HSRUN mode).
3. Cycling endurance is per DFlash or PFlash Sector.
4. Data retention period per block begins upon initial user factory programming or after each subsequent erase. Background maintenance operations during normal FlexRAM usage extend effective data retention life beyond 5 years.
5. FlexMemory write endurance specified for 16-bit and/or 32-bit writes to FlexRAM and is supported across product temperature specification in Normal Mode (not supported in HSRUN mode). Greater write endurance may be achieved with larger ratios of EEPROM backup to FlexRAM.
6. For usage of any EEE driver other than the FlexMemory feature, the endurance spec will fall back to the specified endurance value of the D-Flash specification (1K).
7. [FlexMemory calculator tool](#) is available at NXP web site for help in estimation of the maximum write endurance achievable at specific EEPROM/FlexRAM ratios. The “In Spec” portions of the online calculator refer to the NVM reliability specifications section of data sheet. This calculator is only applies to the FlexMemory feature.

6.3.2 QuadSPI AC specifications

The following table describes the QuadSPI electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.
- Add 50 ohm series termination on board in QuadSPI SCK for Flash A to avoid loop back reflection when using in Internal DQS (PAD Loopback) mode.
- QuadSPI trace length should be 3 inches.
- For non-Quad mode of operation if external device doesn't have pull-up feature, external pull-up needs to be added at board level for non-used pads.
- With external pull-up, performance of the interface may degrade based on load associated with external pull-up.

Table 31. Comparator with 8-bit DAC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit
	Analog comparator hysteresis, Hyst2, Low-speed mode				
	-40 - 125 °C	—	23	80	
V _{HYST3}	Analog comparator hysteresis, Hyst3, High-speed mode				mV
	-40 - 125 °C	—	46	200	
	Analog comparator hysteresis, Hyst3, Low-speed mode				
	-40 - 125 °C	—	32	120	
I _{DAC8b}	8-bit DAC current adder (enabled)				
	3.3V Reference Voltage	—	6	9	μA
	5V Reference Voltage	—	10	16	μA
INL ⁵	8-bit DAC integral non-linearity	−0.75	—	0.75	LSB ⁶
DNL	8-bit DAC differential non-linearity	−0.5	—	0.5	LSB ⁶
t _{DDAC}	Initialization and switching settling time	—	—	30	μs

1. Difference at input > 200mV
2. Applied $\pm (100 \text{ mV} + V_{\text{HYST0}/1/2/3+ \text{ max. of } V_{\text{AIO}})$ around switch point.
3. Applied $\pm (30 \text{ mV} + 2 \times V_{\text{HYST0}/1/2/3+ \text{ max. of } V_{\text{AIO}})$ around switch point.
4. Applied $\pm (100 \text{ mV} + V_{\text{HYST0}/1/2/3})$.
5. Calculation method used: Linear Regression Least Square Method
6. $1 \text{ LSB} = V_{\text{reference}}/256$

NOTE

For comparator IN signals adjacent to V_{DD}/V_{SS} or XTAL/EXTAL or switching pins cross coupling may happen and hence hysteresis settings can be used to obtain the desired comparator performance. Additionally, an external capacitor (1nF) should be used to filter noise on input signal. Also, source drive should not be weak (Signal with < 50 K pull up/down is recommended).

Table 32. LPSPI electrical specifications¹

Num	Symbol	Description	Conditions	Run Mode ²				HSRUN Mode ²				VLPR Mode				Unit
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
	f _{periph} ^{3, 4}	Peripheral Frequency	Slave	-	40	-	40	-	56	-	56	-	4	-	4	MHz
			Master	-	40	-	40	-	56	-	56	-	4	-	4	
			Master Loopback ⁵	-	40	-	48	-	48	-	48	-	4	-	4	
			Master Loopback(slow) ⁶	-	48	-	48	-	48	-	48	-	4	-	4	
1	f _{op}	Frequency of operation	Slave	-	10	-	10	-	14	-	14 ⁷	-	2	-	2	MHz
			Master	-	10	-	10	-	14	-	14 ⁷	-	2	-	2	
			Master Loopback ⁵	-	20	-	12	-	24	-	12	-	2	-	2	
			Master Loopback(slow) ⁶	-	12	-	12	-	12	-	12	-	2	-	2	
2	t _{SPSCK}	SPSCK period	Slave	100	-	100	-	72	-	72	-	500	-	500	-	ns
			Master	100	-	100	-	72	-	72	-	500	-	500	-	
			Master Loopback ⁵	50	-	83	-	42	-	83	-	500	-	500	-	
			Master Loopback(slow) ⁶	83	-	83	-	83	-	83	-	500	-	500	-	
3	t _{Lead} ⁸	Enable lead time (PCS to SPSCK delay)	Slave	-	-	-	-	-	-	-	-	-	-	-	-	ns
			Master	(PCSSCK+1)*t _{periph} -25	-	(PCSSCK+1)*t _{periph} -25	-	(PCSSCK+1)*t _{periph} -25	-	(PCSSCK+1)*t _{periph} -25	(PCSSCK+1)*t _{periph} -50	-	(PCSSCK+1)*t _{periph} -50	-		
			Master Loopback ⁵													
			Master Loopback(slow) ⁶													

Table continues on the next page...

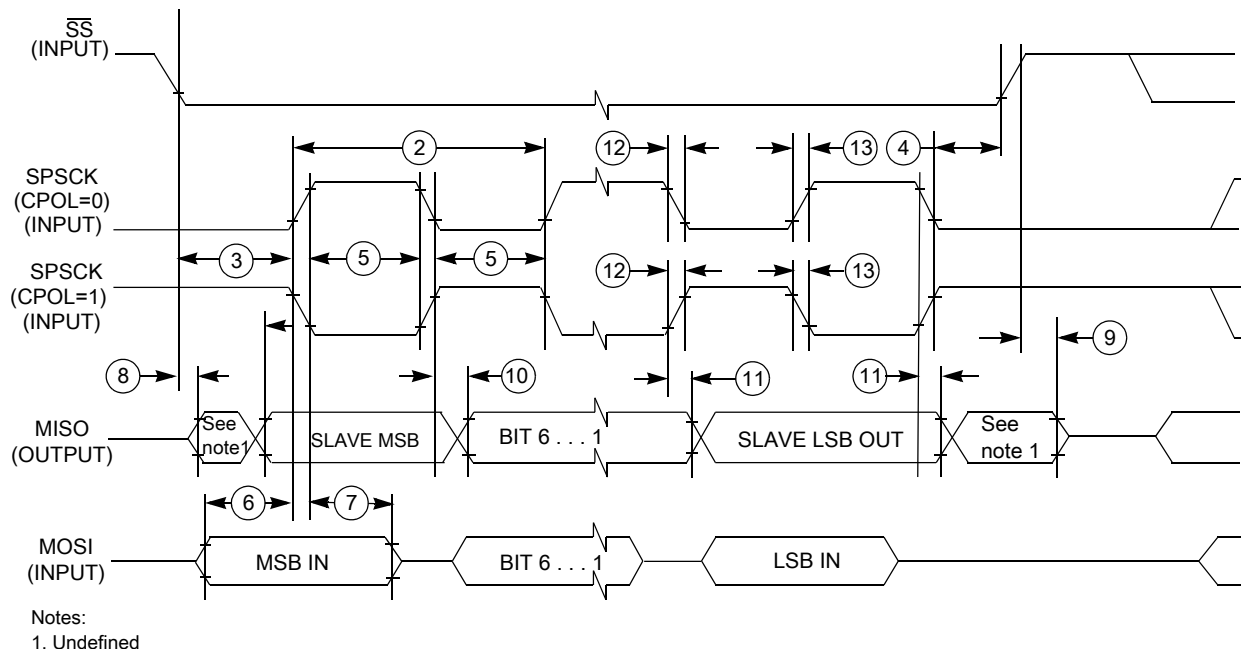


Figure 20. LPSPI slave mode timing (CPHA = 0)

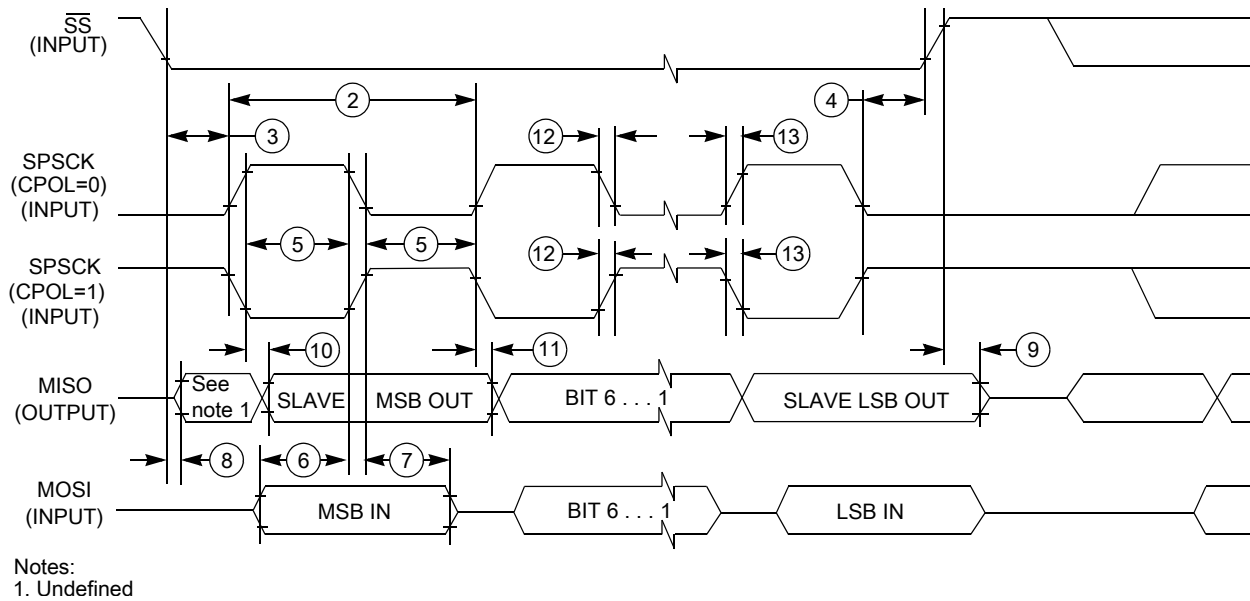


Figure 21. LPSPI slave mode timing (CPHA = 1)

6.5.3 LPI2C electrical specifications

See [General AC specifications](#) for LPI2C specifications.

For supported baud rate see section 'Chip-specific LPI2C information' of the *Reference Manual*.

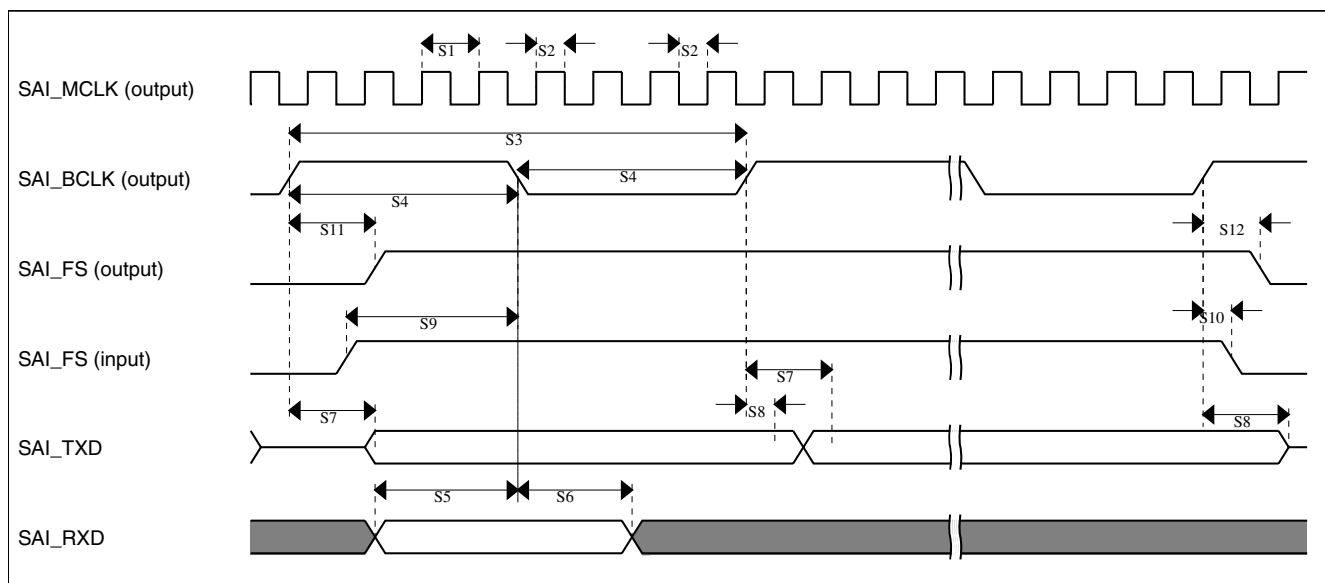


Figure 22. SAI Timing — Master modes

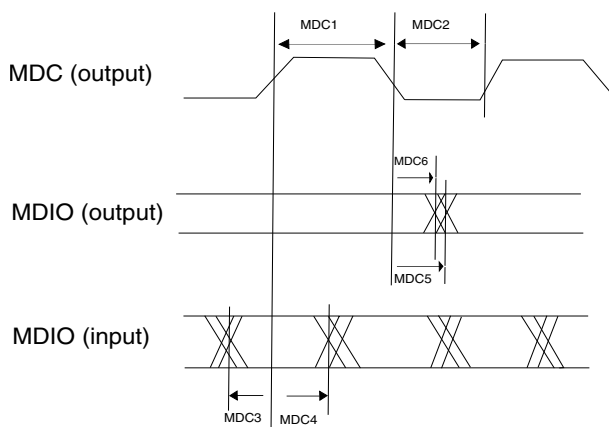
Table 34. Slave mode timing specifications

Symbol	Description	Min.	Max.	Unit
—	Operating voltage	2.97	3.6	V
S13	SAI_BCLK cycle time (input)	80	—	ns
S14 ¹	SAI_BCLK pulse width high/low (input)	45%	55%	BCLK period
S15	SAI_RXD input setup before SAI_BCLK	8	—	ns
S16	SAI_RXD input hold after SAI_BCLK	2	—	ns
S17	SAI_BCLK to SAI_TXD output valid	—	28	ns
S18	SAI_BCLK to SAI_TXD output invalid	0	—	ns
S19	SAI_FS input setup before SAI_BCLK	8	—	ns
S20	SAI_FS input hold after SAI_BCLK	2	—	ns
S21	SAI_BCLK to SAI_FS output valid	—	28	ns
S22	SAI_BCLK to SAI_FS output invalid	0	—	ns

1. The slave mode parameters (S15 - S22) assume 50% duty cycle on SAI_BCLK input. Any change in SAI_BCLK duty cycle input must be taken care during the board design or by the master timing.

Table 37. MDIO timing specifications (continued)

Symbol	Description	Min.	Max.	Unit
MDC1	MDC pulse width high	40%	60%	MDC period
MDC2	MDC pulse width low	40%	60%	MDC period
MDC3	MDIO (input) to MDC rising edge setup	25	—	ns
MDC4	MDIO (input) to MDC rising edge hold	0	—	ns
MDC5	MDC falling edge to MDIO output valid (maximum propagation delay)	—	25	ns
MDC6	MDC falling edge to MDIO output invalid (minimum propagation delay)	-10	—	ns

**Figure 28. MII/RMII serial management channel timing diagram**

6.5.7 Clockout frequency

Maximum supported clock out frequency for this device is 20 MHz

6.6 Debug modules

6.6.1 SWD electrical specifications

7.3 General notes for specifications at maximum junction temperature

An estimation of the chip junction temperature, T_J , can be obtained from this equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

- T_A = ambient temperature for the package (°C)
- $R_{\theta JA}$ = junction to ambient thermal resistance (°C/W)
- P_D = power dissipation in the package (W)

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. Unfortunately, there are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. For packages such as the PBGA, these values can be different by a factor of two. Which value is closer to the application depends on the power dissipated by other components on the board. The value obtained on a single layer board is appropriate for the tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated.

When a heat sink is used, the thermal resistance is expressed in the following equation as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

- $R_{\theta JA}$ = junction to ambient thermal resistance (°C/W)
- $R_{\theta JC}$ = junction to case thermal resistance (°C/W)
- $R_{\theta CA}$ = case to ambient thermal resistance (°C/W)

$R_{\theta JC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To determine the junction temperature of the device in the application when heat sinks are not used, the Thermal Characterization Parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using this equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

- T_T = thermocouple temperature on top of the package ($^{\circ}\text{C}$)
- Ψ_{JT} = thermal characterization parameter ($^{\circ}\text{C}/\text{W}$)
- P_D = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

8 Dimensions

8.1 Obtaining package dimensions

Package dimensions are provided in the package drawings.

To find a package drawing, go to <http://www.nxp.com> and perform a keyword search for the drawing's document number:

Package option	Document Number
32-pin QFN	SOT617-3 ¹
48-pin LQFP	98ASH00962A
64-pin LQFP	98ASS23234W
100-pin LQFP	98ASS23308W
100-pin MAPBGA	98ASA00802D
144-pin LQFP	98ASS23177W
176-pin LQFP	98ASS23479W

1. 5x5 mm package

Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> Updated values for V_{REFH} and V_{REFL} to add reference to the section "voltage and current operating requirements" for Min and Max values Updated footnote to Typ. Removed footnote from RAS Analog source resistance Updated figure: ADC input impedance equivalency diagram In table: 12-bit ADC characteristics (2.7 V to 3 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) <ul style="list-style-type: none"> Removed rows for V_{TEMP_S} and V_{TEMP25} Updated footnote to Typ. In table: 12-bit ADC characteristics (3 V to 5.5 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) <ul style="list-style-type: none"> Removed rows for V_{TEMP_S} and V_{TEMP25} Removed number for TUE Updated footnote to Typ. In table: Comparator with 8-bit DAC electrical specifications <ul style="list-style-type: none"> Updated Typ. of I_{DDL5} Supply current, Low-speed mode Updated Typ. of t_{DLSB} Propagation delay, Low-speed mode Updated Typ. of t_{DHSS} Propagation delay, High-speed mode Updated t_{DLSS} Propagation delay Added row for t_{DDAC} Initialization and switching settling time Updated footnote Updated section LPSPi electrical specifications Added section: SAI electrical specifications Updated section: Ethernet AC specifications Added section: Clockout frequency Added section: Trace electrical specifications Updated table: Table 41 : Updated numbers for S32K142 and S32K148 Updated table: Table 42 : Updated numbers for S32K148 Updated Document number for 32-pin QFN in topic Obtaining package dimensions
3	14 March 2017	<ul style="list-style-type: none"> In Table 2 <ul style="list-style-type: none"> Updated min. value of V_{DD_OFF} Added parameter I_{INJSUM_AF} Updated Power mode transition operating behaviors Updated Power consumption Updated footnote to T_{SPLL_LOCK} in SPLL electrical specifications In 12-bit ADC electrical characteristics <ul style="list-style-type: none"> Updated table: 12-bit ADC characteristics (2.7 V to 3 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) <ul style="list-style-type: none"> Added typ. value to I_{DDA_ADC}, TUE, DNL, and INL Added min. value to SMPLTS Removed footnote 'All the parameters in this table ... ' Updated table: 12-bit ADC characteristics (3 V to 5.5 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) <ul style="list-style-type: none"> Added typ. value to I_{DDA_ADC} Removed footnote 'All the parameters in this table ... ' In Flash timing specifications — commands updated Max. value of t_{Vfykey} to 33 μs
4	02 June 2017	<ul style="list-style-type: none"> In section: Block diagram, added block diagram for S32K11x series. Updated figure: S32K1xx product series comparison. In section: Selecting orderable part number , added reference to attachment S32K_Part_Numbers.xlsx. In section: Ordering information <ul style="list-style-type: none"> Updated figure: Ordering information. In Table 1,

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Table 43. Revision History

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> Added footnote 'For S32K11x – FIRC/SOSC/FIRC/LPO; For S32K14x – FIRC/SOSC/FIRC/LPO/SPLL' to 'VLPS Mode: All clock sources disabled' Updated numbers for: <ul style="list-style-type: none"> VLPR → VLPS VLPS → VLPR 'RUN → Compute operation' RUN → VLPS RUN → VLPR In Power consumption : <ul style="list-style-type: none"> Updated specs for S32K142, S32K144, and S32K148 Updated footnote 'Typical current numbers are indicative ...' Updated footnote 'The S32K148 data ...' Removed footnote 'Above S32K148 data is preliminary targets only' Added new table 'Power consumption at 3.3 V' In General AC specifications : <ul style="list-style-type: none"> Updated max value and footnote of WFRST Updated symbol for not filtered pulse to 'WNFRST', updated min value, removed max. value, and added footnote Fixed naming conventions to align with DS in DC electrical specifications at 3.3 V Range and DC electrical specifications at 5.0 V Range Updated specs for AC electrical specifications at 3.3 V range and AC electrical specifications at 5 V range In Device clock specifications : <ul style="list-style-type: none"> Updated f_{BUS} to 48 for 11x Added footnote to f_{BUS} for 14x In External System Oscillator frequency specifications : <ul style="list-style-type: none"> Added specs for S32K11x Updated 't_{dc_extal}' for S32K14x Added footnote 'Frequencies below ...' to 'f_{ec_extal}' and 't_{dc_extal}' Splitted Flash timing specifications — commands for S32K14x and S32K11x Updated Flash timing specifications — commands for S32K14x In Reliability specifications : <ul style="list-style-type: none"> Added footnote 'Data retention period ...' for 'tnvmretp1k' and 'tnvmreteet' Minor update in footnote for 'nnvmwree16' 'nnvmwree256' In QuadSPI AC specifications : <ul style="list-style-type: none"> Updated 'MCR[SCLKCFG[5]]' value to 0 Updated 'Data Input Setup Time' HSRUN Internal DQS PAD Loopback value to 1.6 Updated 'Data Input Setup Time' DDR External DQS min. value to 2 Updated 'Data Input Hold Time' DDR External DQS min. value to 20 Updated figure 'QuadSPI output timing (SDR mode) diagram' and 'QuadSPI input timing (HyperRAM mode) diagram' In 12-bit ADC electrical characteristics : <ul style="list-style-type: none"> Added note 'On reduced pin packages where ...' Removed max. value of 'I_{DDA_ADC}' Added note 'Due to triple ...' In 12-bit ADC operating conditions, removed parameter 'ΔV_{DDA}' In CMP with 8-bit DAC electrical specifications : <ul style="list-style-type: none"> Updated Typ. and Max. values of 'I_{DDL5}' Updated Typ. value of 't_{DHSB}' Updated Typ. value of 'V_{HYST1}', 'V_{HYST2}', and 'V_{HYST3}' In LPSPFI electrical specifications : <ul style="list-style-type: none"> Updated 'f_{periph}' and 'f_{op}', and 't_{SPSCK}'

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Table 43. Revision History

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> Updated specs for T_{JIT} Cycle-to-Cycle jitter to 300 ps In QuadSPI AC specifications : <ul style="list-style-type: none"> Updated specs for T_{iv} Data Output In-Valid Time In figure 'QuadSPI output timing (SDR mode) diagram', marked Invalid area In CMP with 8-bit DAC electrical specifications : <ul style="list-style-type: none"> Removed '(VAIO)' from decription of V_{HYST0} In LPSPi electrical specifications : <ul style="list-style-type: none"> Added note 'Undefined' in figures 'LPSPi slave mode timing (CPHA = 0)' and 'LPSPi slave mode timing (CPHA = 1)'